

BAS32L High-speed switching diode Rev. 06 – 29 October 2008

Product data sheet

1. Product profile

1.1 General description

Single high-speed switching diode, fabricated in planar technology, and encapsulated in a small hermetically sealed glass SOD80C Surface-Mounted Device (SMD) package.

1.2 Features

- High switching speed: $t_{rr} \le 4$ ns
- Reverse voltage: $V_R \le 75 \text{ V}$
- Repetitive peak reverse voltage: V_{RRM} ≤ 100 V
- Repetitive peak forward current: I_{FRM} ≤ 450 mA
- Small hermetically sealed glass SMD package

1.3 Applications

- High-speed switching
- Reverse polarity protection

1.4 Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|------------------------------------|-------------------------|--------------|-----|------|------|
| I _F | forward current | | <u>[1]</u> _ | - | 200 | mA |
| I _{FRM} | repetitive peak forward current | | - | - | 450 | mA |
| V _R | reverse voltage | | - | - | 75 | V |
| V _F | forward voltage | I _F = 100 mA | - | - | 1000 | mV |
| t _{rr} | reverse recovery time | | [2] _ | - | 4 | ns |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 $\Omega;$ measured at I_R = 1 mA.



2. Pinning information

| Table 2. | Pinning | | |
|----------|-------------|--------------------|------------------|
| Pin | Description | Simplified outline | Graphic symbol |
| 1 | cathode | [1] | |
| 2 | anode | k | 1 2 006aab040 |

[1] The marking band indicates the cathode.

3. Ordering information

| Table 3. Order | ing information | lion | |
|----------------|-----------------|--|---------|
| Type number | Package | | |
| | Name | Description | Version |
| BAS32L | - | hermetically sealed glass surface-mounted package; 2 connectors | SOD80C |

4. Marking

| Table 4. | Marking codes | | |
|----------|---------------|-----------------------------|--|
| Type num | iber | Marking code ^[1] | |
| BAS32L | | marking band | |
| | | | |

[1] black: made in Philippines brown: made in China

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|------------------------------------|----------------------------|--------------|-----|------|
| V _{RRM} | repetitive peak reverse voltage | | - | 100 | V |
| V _R | reverse voltage | | - | 75 | V |
| I _F | forward current | | <u>[1]</u> _ | 200 | mA |
| I _{FRM} | repetitive peak forward current | | - | 450 | mA |
| I _{FSM} | non-repetitive peak forward | square wave | [2] | | |
| | current | t _p = 1 μs | - | 4 | А |
| | | t _p = 1 ms | - | 1 | А |
| | | t _p = 1 s | - | 0.5 | А |
| P _{tot} | total power dissipation | $T_{amb} = 25 \ ^{\circ}C$ | <u>[1]</u> _ | 500 | mW |

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| Table 5. | Limiting | values | continued |
|----------|----------|--------|-----------|
|----------|----------|--------|-----------|

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|----------------------|------------|-----|------|------|
| Тj | junction temperature | | - | 200 | °C |
| T _{amb} | ambient temperature | | -65 | +200 | °C |
| T _{stg} | storage temperature | | -65 | +200 | °C |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] $T_j = 25 \,^{\circ}C$ prior to surge.

6. Thermal characteristics

| Table 6. | Thermal characteristics | | | | | |
|-----------------------|--|-------------|--------------|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | <u>[1]</u> - | - | 350 | K/W |
| R _{th(j-sp)} | thermal resistance from junction to solder point | | - | - | 300 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

Table 7.Characteristics

 $T_{amb} = 25 \circ C$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------------------------------|--------------------------|--|--------------|------|-----|------|
| V _F | forward voltage | I _F = 5 mA | 620 | - | 750 | mV |
| | I _F = 100 mA | - | - | 1000 | mV | |
| | | $I_F = 100 \text{ mA}; \text{ T}_j = 100 ^{\circ}\text{C}$ | - | - | 930 | mV |
| I _R reverse current | V _R = 20 V | - | - | 25 | nA | |
| | V _R = 75 V | - | - | 5 | μΑ | |
| | | V_R = 20 V; T_j = 150 °C | - | - | 50 | μΑ |
| | | V_R = 75 V; T_j = 150 °C | - | - | 100 | μΑ |
| C _d | diode capacitance | V _R = 0 V; f = 1 MHz | - | - | 2 | pF |
| t _{rr} | reverse recovery time | | <u>[1]</u> _ | - | 4 | ns |
| V_{FR} | forward recovery voltage | | [2] _ | - | 2.5 | V |

[1] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 $\Omega;$ measured at I_R = 1 mA.

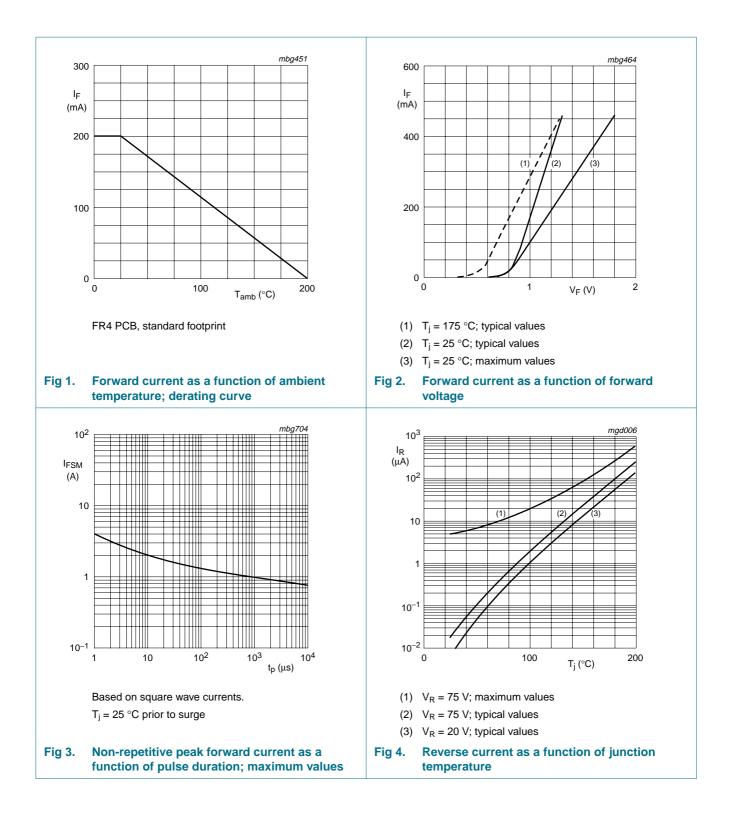
[2] When switched from $I_F = 50$ mA; $t_r = 20$ ns.

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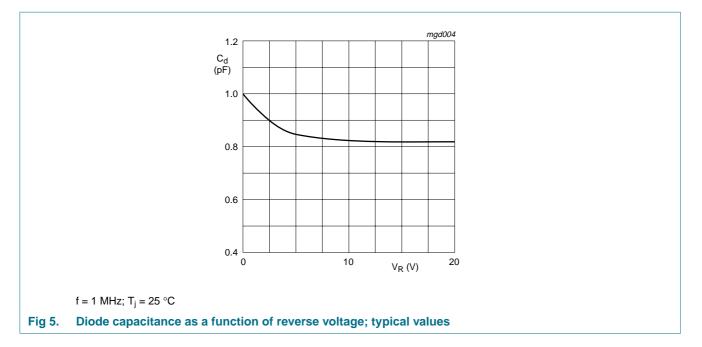


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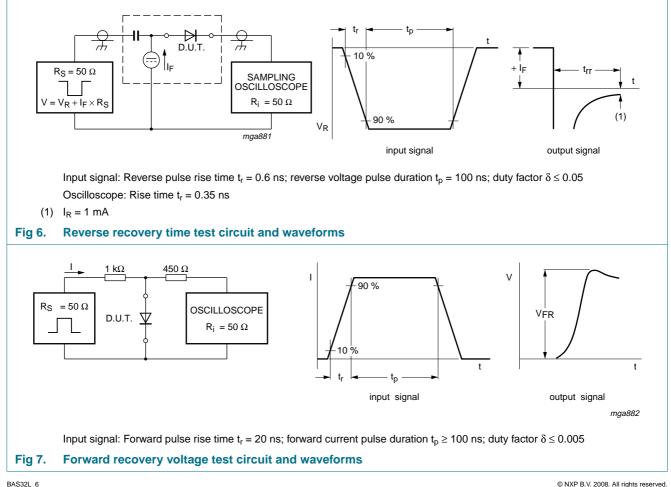
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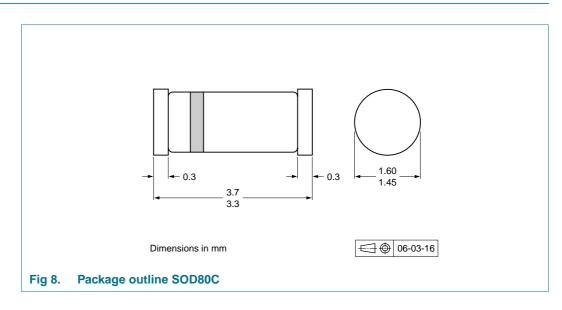


Test information 8.



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9. Package outline



10. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

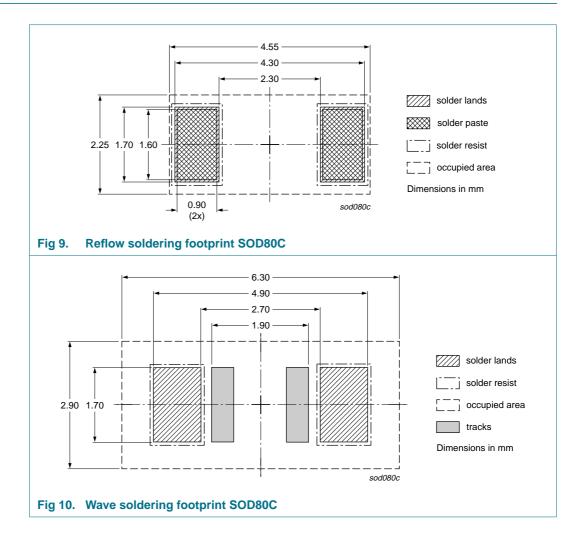
| Type number | Package | Description | Packing qua | Intity |
|-------------|---------|--------------------------------|-------------|--------|
| | | | 2500 | 10000 |
| BAS32L | SOD80C | 4 mm pitch, 8 mm tape and reel | -115 | -135 |

[1] For further information and the availability of packing methods, see Section 14.

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11. Soldering



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12. Revision history

| Table 9. Revision I | nistory | | | |
|---------------------|----------------------------------|-----------------------------|---------------|------------|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| BAS32L_6 | 20081029 | Product data sheet | - | BAS32L_5 |
| Modifications: | Figure 8: an | nended | | |
| | Section 13 ' | Legal information": updated | l | |
| BAS32L_5 | 20080103 | Product data sheet | - | BAS32L_4 |
| BAS32L_4 | 20050322 | Product data sheet | - | BAS32L_3 |
| BAS32L_3 | 20020123 | Product specification | - | BAS32L_2 |
| BAS32L_2 | 19960910 | Product specification | - | BAS32L_1 |
| BAS32L_1 | 19960423 | Product specification | - | - |
| | | | | |

13. Legal information

13.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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